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<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> (use as many sheets as necessary)		Application Number	Based on 10/265,634 10/77/80		
		Filing Date	October 8, 2002		
		First Named Inventor	Hidekazu MIYAIRI, et al.		
		Group Art Unit	2826 2823		
		Examiner Name	Fetsum Abraham William Brewster		
Sheet	1	of	1	Attorney Docket Number	0756-7253

U.S. PATENT DOCUMENTS						
Examiner Initials <sup>1</sup>	Cite. No. <sup>1</sup>	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code <sup>2</sup> (if known)			
QVA	X	5,643,826	X	Ohtani et al.	07/01/97	436/162
QVB		5,352,291	B1	Zhang et al.	04/18/00	117/8
QVB		5,352,291	X	Zhang et al.	10/04/94	117/8
QVB		5,578,520		Zhang et al.	11/26/96	438/487
QVB		6,027,960		Kusumoto et al.	02/22/00	438/166
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QVB		6,242,292		Yamazaki et al.	06/05/01	438/166
QVB		5,789,284		Yamazaki et al.	08/04/98	438/166
QVB		5,683,937		Furukawa et al.	11/04/97	438/42
QVB	X	5,880,487	X	Furukawa et al.	03/09/99	257/94

FOREIGN PATENT DOCUMENTS							
Examiner Initials <sup>1</sup>	Cite. No. <sup>1</sup>	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Office <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)			
QVB	X	JP	08-078329	X	X	03/22/96	X Abst.
QVB	X	JP	2001-60551	X	X	03/06/01	X Full
QVB	X	JP	07-183540	X	X	07/21/95	X Abst.

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials <sup>1</sup>	Cite. No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
QVB	X	Katsuyuki SUGA et al., "P-3: The Effect of a Laser Annealing Ambient on the Morphology and TFT Performance of Poly-Si Films," SID 00 DIGEST, pp. 534-537.	X

Examiner Signature	William M. Brewster	Date Considered	17 AUG 03
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